BLF7G27L-135

Power LDMOS transistor Rev. 1 — 1 November 2011

1. Product profile

1.1 General description

135 W LDMOS power transistor for base station applications at frequencies from 2600 MHz to 2700 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25 \ ^{\circ}C$ in a common source class-AB production test circuit.

Mode of operation	f	I _{Dq}	v_{ds}	P _{L(AV)}	Gp	η	ACPR _{885k}	$ACPR_{5M}$
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)
IS-95	2600 to 2700	1300	28	25	16.5	24	-45 <mark>[1]</mark>	-
Single carrier W-CDMA	2600 to 2700	1300	28	45	16.5	30	-	-30 <mark>[2]</mark>

[1] Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

[2] 3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for W-CDMA base stations and multi carrier applications in the 2600 MHz to 2700 MHz frequency range



2. Pinning information

Pin	Description		Simplified outline	Graphic symbol
1	drain			_
2	gate			1 لــــا
3	source	<u>[1]</u>		2

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information					
Type number	Packag	ge			
	Name	Description	Version		
BLF7G27L-135	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A		

4. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	N	lin	Max	Unit
V _{DS}	drain-source voltage		-		65	V
V _{GS}	gate-source voltage		_	0.5	+13	V
I _D	drain current		-		28	А
T _{stg}	storage temperature		_	65	+150	°C
Tj	junction temperature		-		200	°C

5. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 35 W	0.28	K/W

6. Characteristics

Table 6. $T_j = 25 \ ^{\circ}C$	Characteristics Cunless otherwise specified.					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V_{GS} = 0 V; I_D = 1 mA	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 216 mA	1.5	1.8	2.3	V
I _{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 28 V	-	-	5	μA
I _{DSX}	drain cut-off current	$\label{eq:VGS} \begin{array}{l} V_{GS} = V_{GS(th)} + 3.75 \; V; \\ V_{DS} = 10 \; V \end{array}$	34.2	40.5	-	A
I _{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	500	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 216 mA	-	1.87	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 7.56 A$	-	0.07	-	Ω

7. Test information

Remark: All testing performed in a class-AB production test circuit.

Table 7. Functional test information

Mode of operation: 1-carrier N-CDMA, single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF, channel bandwidth is 1.2288 MHz; $f_1 = 2600$ MHz; $f_2 = 2700$ MHz; RF performance at $V_{DS} = 28$ V; $I_{Dq} = 1300$ mA; $T_{case} = 25$ °C; unless otherwise specified.

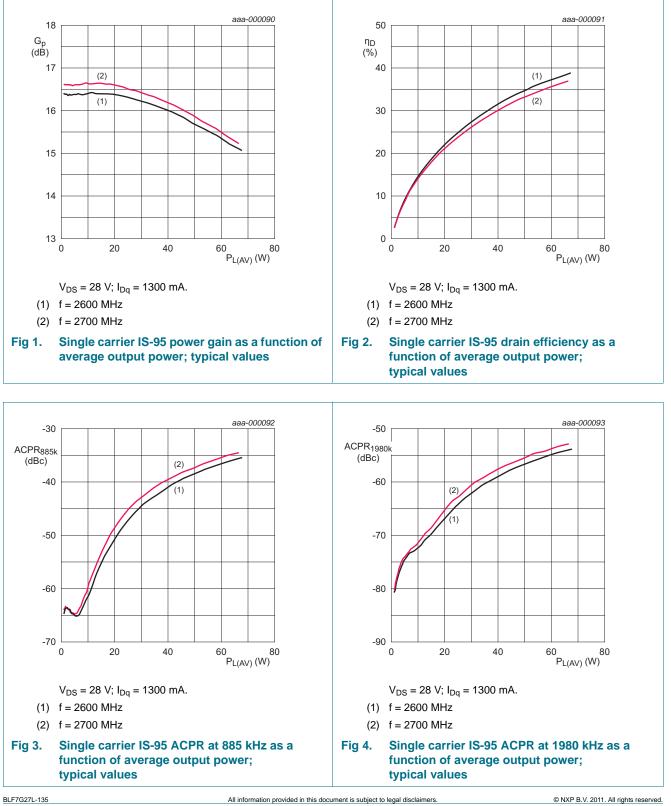
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
P _{L(AV)}	average output power		-	25	-	W
Gp	power gain		14.8	16.5	17.7	dB
RL _{in}	input return loss		-	-12	-	dB
η_D	drain efficiency		20	24	-	%
ACPR _{885k}	adjacent channel power ratio (885 kHz)		-	-45	-40	dBc

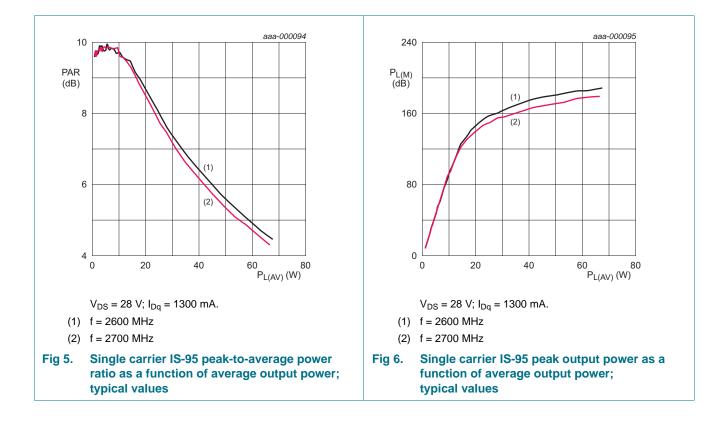
7.1 Ruggedness in class-AB operation

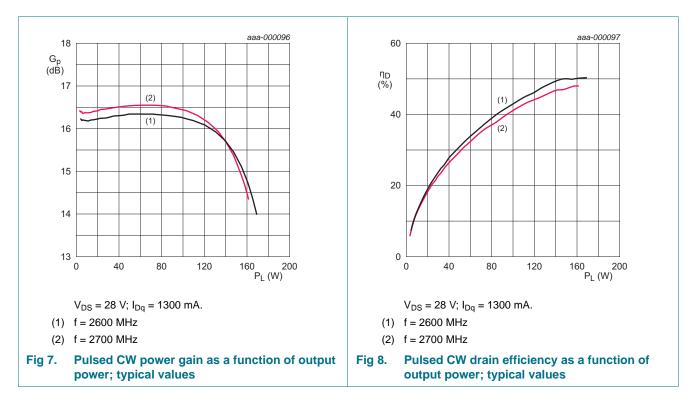
The BLF7G27L-135 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 1300 mA; P_L = 135 W (CW); f = 2600 MHz.

7.2 Single carrier IS-95

Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.



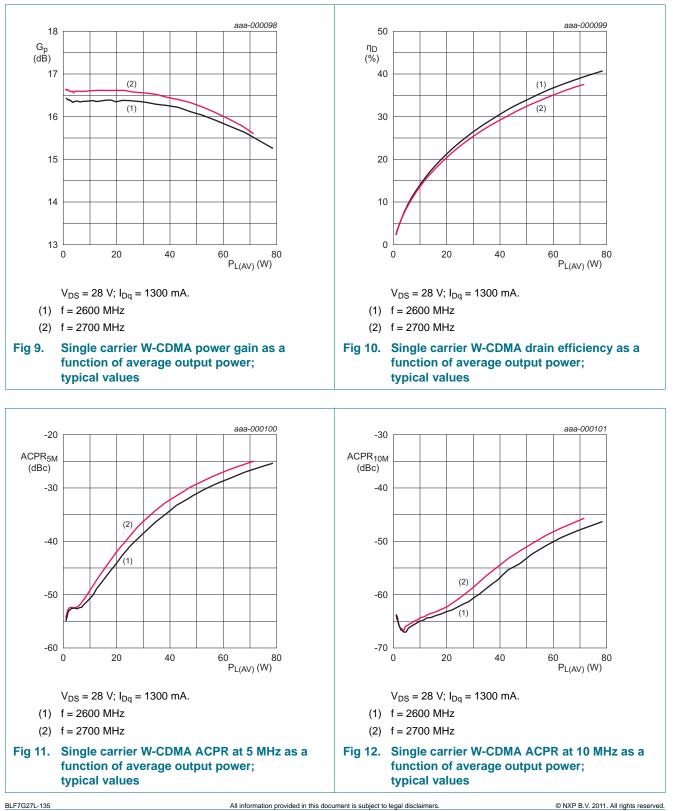




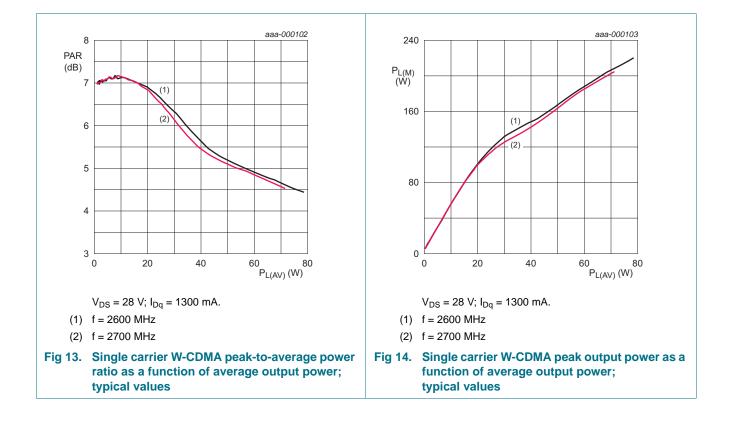
7.3 Pulsed CW

7.4 Single carrier W-CDMA

3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.



Power LDMOS transistor



8. Package outline

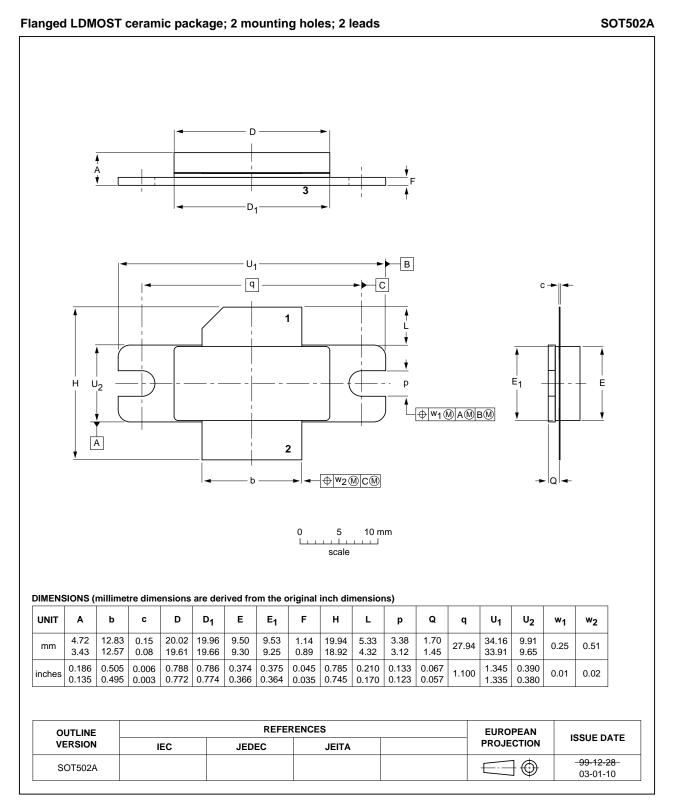


Fig 15. Package outline SOT502A

9. Abbreviations

Table 8.	Abbreviations
Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
N-CDMA	Narrowband Code Division Multiple Access
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

10. Revision history

Table 9.	Revision history					
Document	ID	Release date	Data sheet status	Change notice	Supersedes	
BLF7G27L-	-135 v.1	20111101	Objective data sheet	-	-	

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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